Dual P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
–20	0.490 @ V_{GS} = –4.5 V	–1.0
	0.750 @ V_{GS} = –2.5 V	–0.81
	1.10 @ V_{GS} = –1.8 V	–0.67

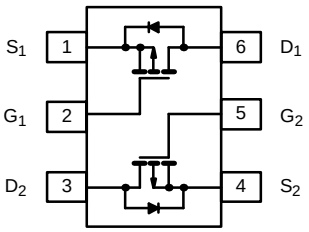
FEATURES

- TrenchFET® Power MOSFETS: 1.8-V Rated
- ESD Protected: 3000 V
- Thermally Enhanced SC-70 Package

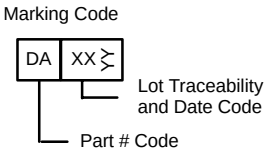
APPLICATIONS

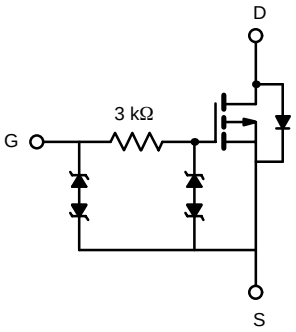
- Load Switching
- PA Switch
- Level Switch

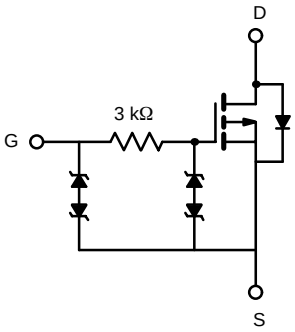
SOT-363
SC-70 (6-LEADS)



Top View







ABSOLUTE MAXIMUM RATINGS (T_A = 25°C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	5 secs	Steady State	Unit
Drain-Source Voltage		V_{DS}	–20		V
Gate-Source Voltage		V_{GS}	±12		
Continuous Drain Current (T_J = 150°C)[a]	T_A = 25°C	I_D	–1.0	–0.88	A
	T_A = 85°C		–0.72	–0.63	
Pulsed Drain Current		I_{DM}	–3		
Continuous Diode Current (Diode Conduction)[a]		I_S	–0.61	–0.48	
Maximum Power Dissipation[a]	T_A = 25°C	P_D	0.74	0.57	W
	T_A = 85°C		0.38	0.30	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	–55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient[a]	t ≤ 5 sec	R_{thJA}	130	170	°C/W
	Steady State		170	220	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	80	100	

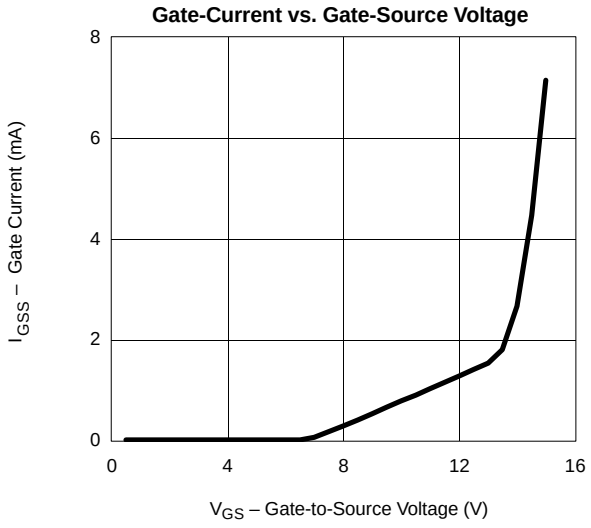
Notes
a. Surface Mounted on 1” x 1” FR4 Board.

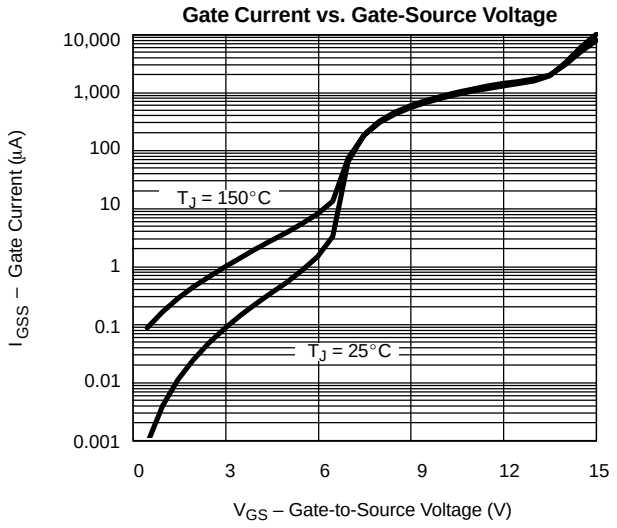
SPECIFICATIONS (T_J = 25°C UNLESS OTHERWISE NOTED)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = –100 µA	–0.45			V
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ±4.5 V			±1.5	µA
		V_{DS} = 0 V, V_{GS} = ±12 V			±10	mA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = –16 V, V_{GS} = 0 V			–1	µA
		V_{DS} = –16 V, V_{GS} = 0 V, T_J = 85°C			–5	
On-State Drain Current[a]	$I_{D(on)}$	V_{DS} = –5 V, V_{GS} = –4.5 V	–2			A
Drain-Source On-State Resistance[a]	$r_{DS(on)}$	V_{GS} = –4.5 V, I_D = –0.88 A		0.400	0.490	Ω
		V_{GS} = –2.5 V, I_D = –0.71 A		0.610	0.750	
		V_{GS} = –1.8 V, I_D = –0.2 A		0.850	1.10	
Forward Transconductance[a]	g_{fs}	V_{DS} = –10 V, I_D = –0.88 A		1.5		S
Diode Forward Voltage[a]	V_{SD}	I_S = –0.47 A, V_{GS} = 0 V		–0.85	–1.2	V
Dynamic[b]						
Total Gate Charge	Q_g	V_{DS} = –10 V, V_{GS} = –4.5 V, I_D = –0.88 A		1.2	1.8	nC
Gate-Source Charge	Q_{gs}			0.3		
Gate-Drain Charge	Q_{gd}			0.3		
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = –10 V, R_L = 20 Ω I_D ≅ –0.5 A, V_{GEN} = –4.5 V, R_G = 6 Ω		0.150	0.23	µs
Rise Time	t_r			0.480	0.72	
Turn-Off Delay Time	$t_{d(off)}$			0.840	1.2	
Fall Time	t_f			0.850	1.2	

Notes
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.

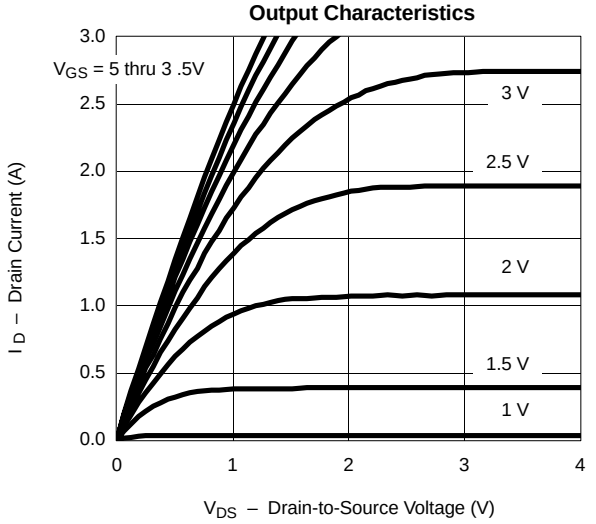
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



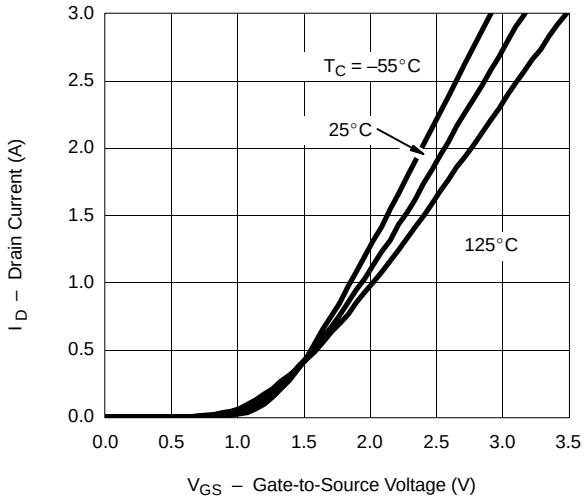


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

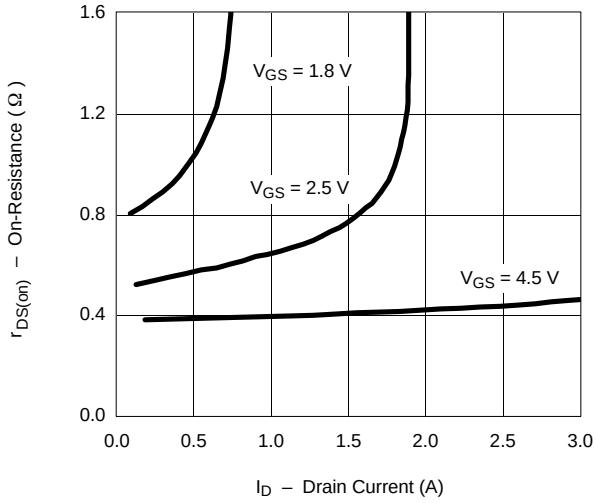
Output Characteristics



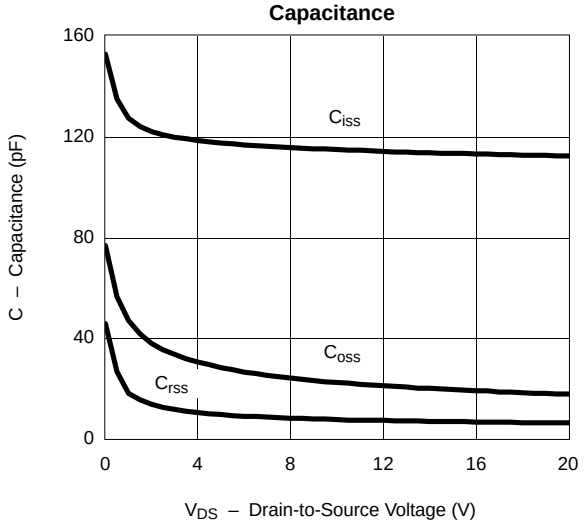
Transfer Characteristics



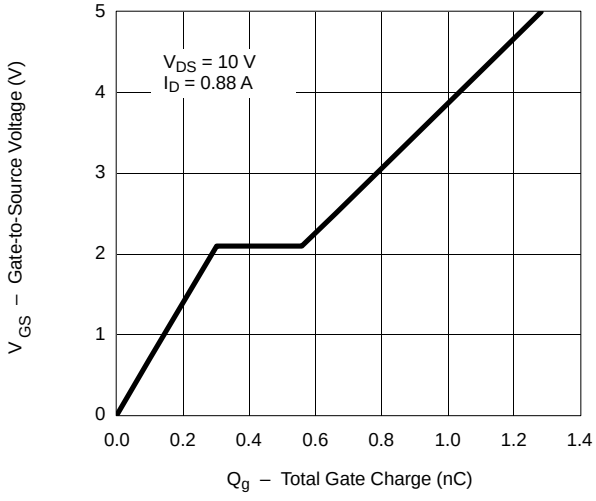
On-Resistance vs. Drain Current



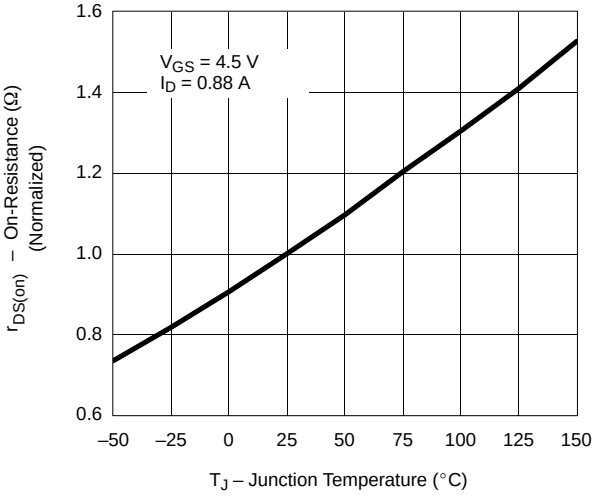
Capacitance



Gate Charge

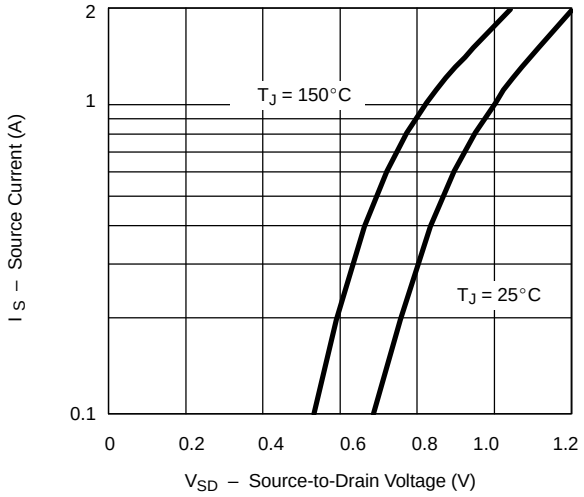


On-Resistance vs. Junction Temperature

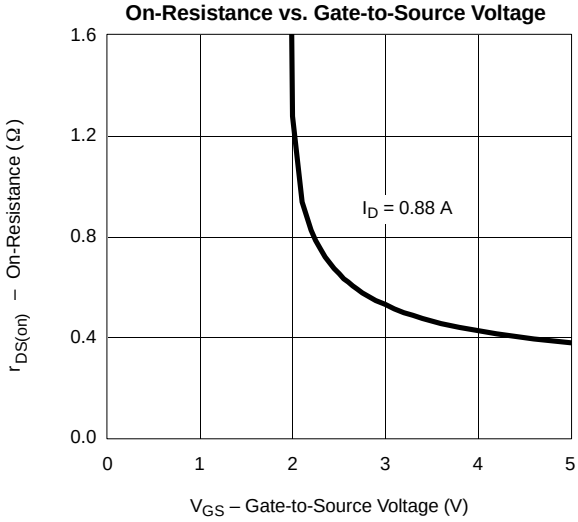


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

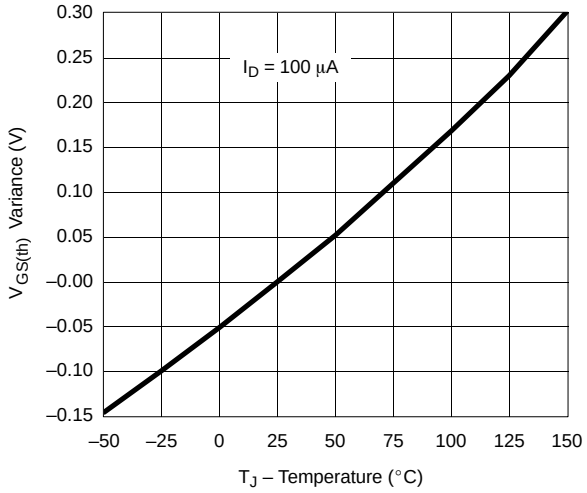
Source-Drain Diode Forward Voltage



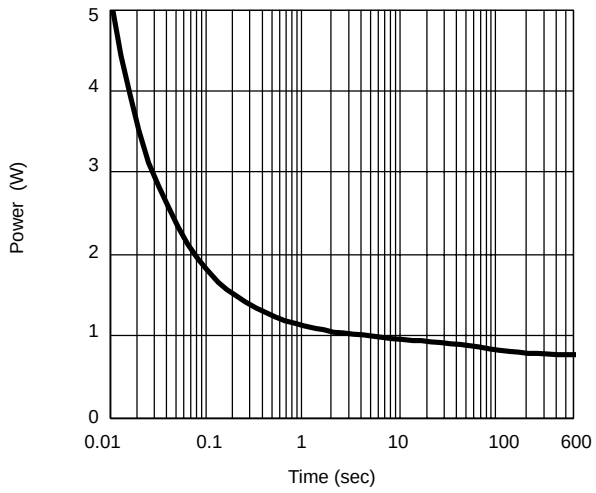
On-Resistance vs. Gate-to-Source Voltage



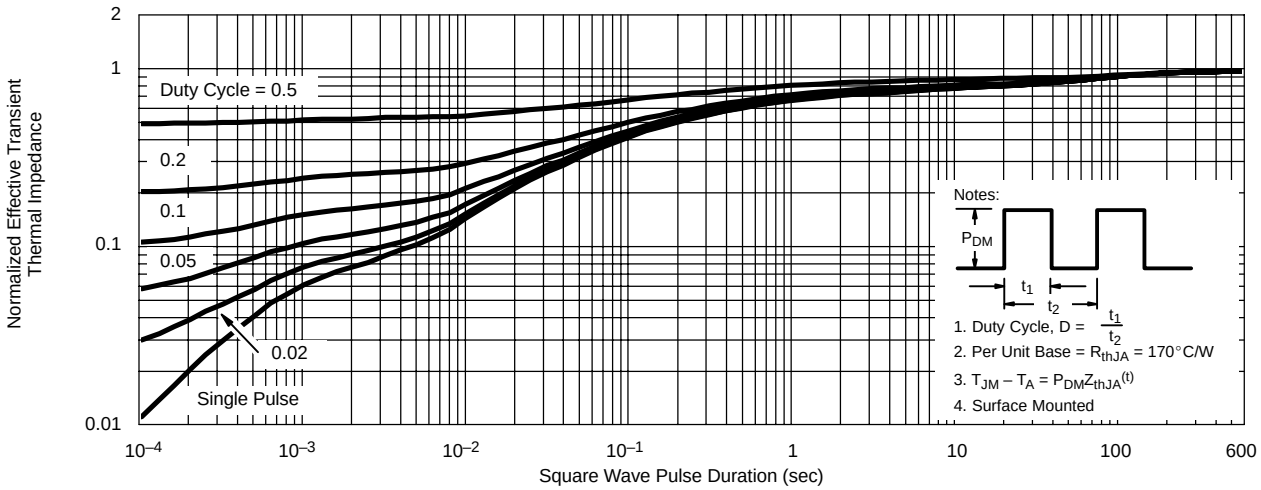
Threshold Voltage



Single Pulse Power, Junction-to-Ambient

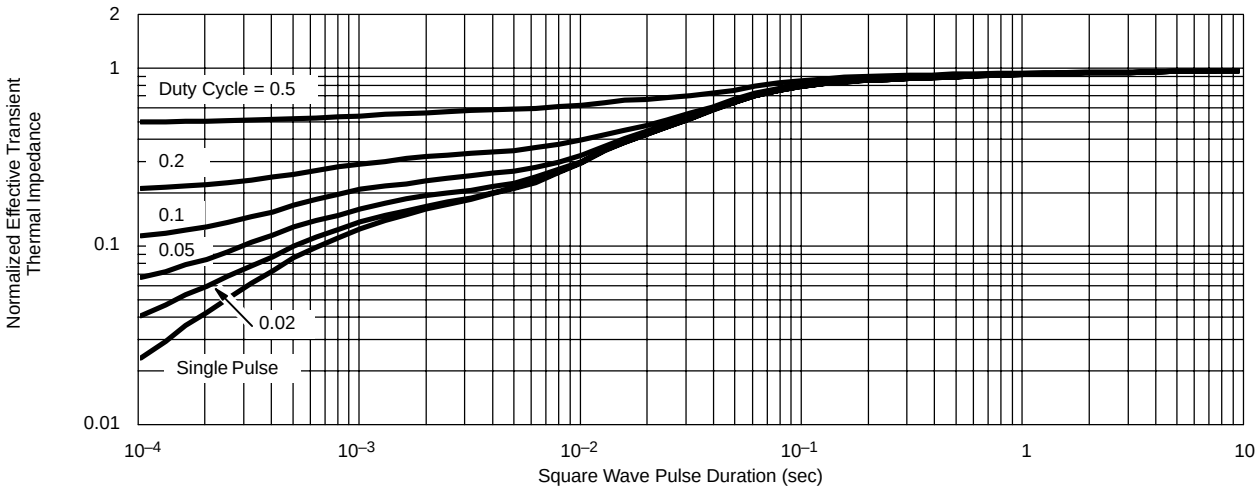


Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

Normalized Thermal Transient Impedance, Junction-to-Foot



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